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## 11.3-GBPS DIFFERENTIAL VCSEL DRIVER

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### FEATURES

- Up to 11.3-Gbps Operation
- Two-Wire Digital Interface
- Digitally Selectable Modulation Current up to 40 mA
- Digitally Selectable Bias Current up to 20 mA
- Automatic Power Control (APC) Loop
- Supports Transceiver Management System (TMS)
- Programmable Input Equalizer
- Includes Laser Safety Features
- Analog Temperature Sensor Output
- Single 3.3-V Supply
- Operating Temperature  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$
- Surface-Mount, Small-Footprint, 4-mm  $\times$  4-mm, 20-Pin QFN Package

### APPLICATIONS

- 10-Gigabit Ethernet Optical Transmitters
- 8 $\times$  and 10 $\times$  Fibre Channel Optical Transmitters
- SONET OC-192/SDH STM-64 Optical Transmitters
- XFP and SFP+ Transceiver Modules
- XENPAK, XPAK, X2, and 300-Pin MSA Transponder Modules

### DESCRIPTION

The ONET1191V is a high-speed, 3.3-V laser driver designed to directly modulate VCSELs at data rates up to 11.3 Gbps.

The device provides a two-wire serial interface which allows digital control of the modulation and bias currents, eliminating the need for external components. An optional input equalizer can be used for equalization of up to 300 mm (12 inches) of microstrip or stripline transmission line on FR4 printed-circuit boards.

The ONET1191V includes an integrated automatic power control (APC) loop as well as circuitry to support laser safety and transceiver management systems.

The VCSEL driver is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  ambient temperatures and is available in a small-footprint, 4-mm  $\times$  4-mm, 20-pin QFN package.



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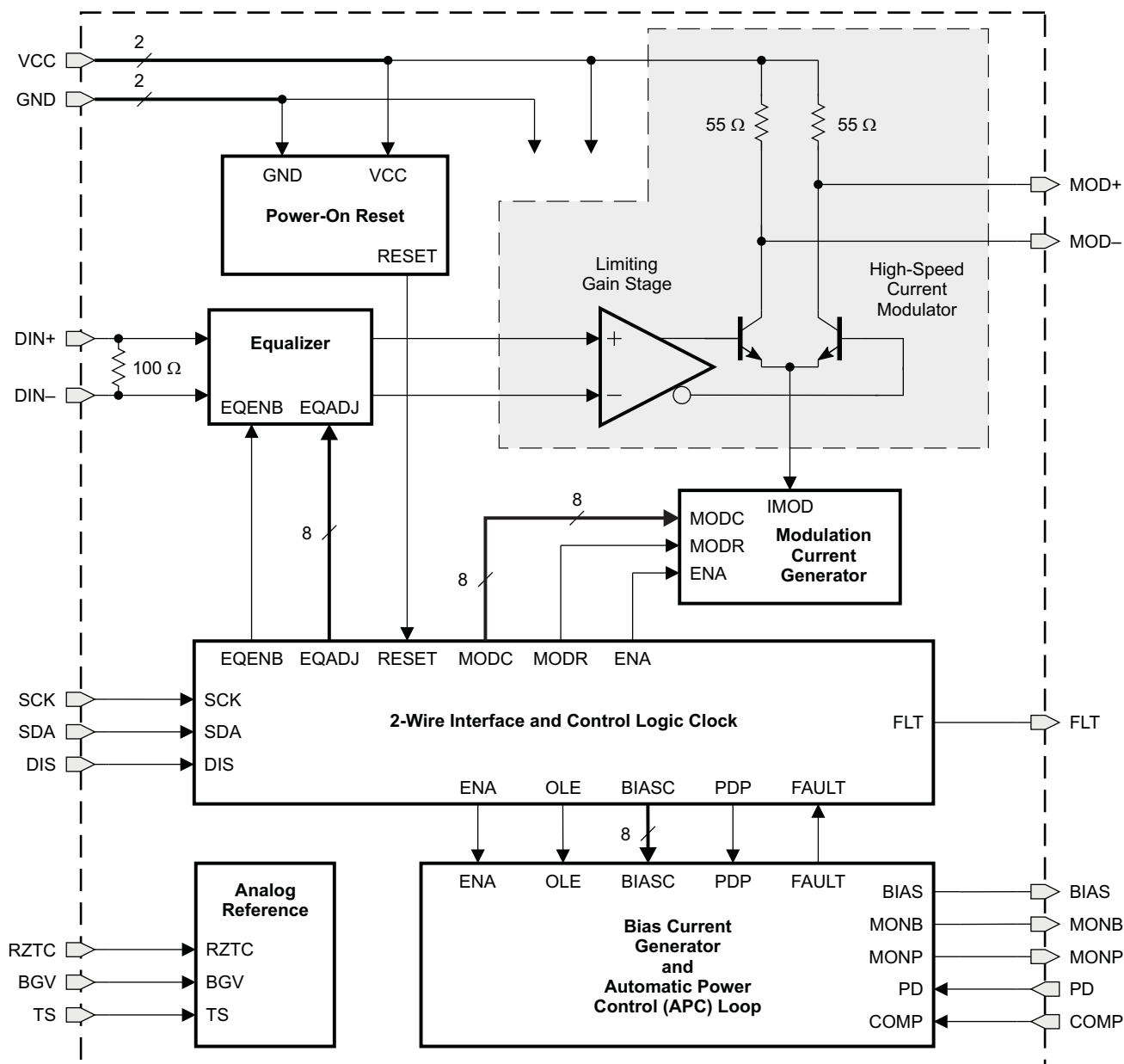


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## BLOCK DIAGRAM

A simplified block diagram of the ONET1191V is shown in Figure 1.

The VCSEL driver consists of an equalizer, a high-speed current modulator, a modulation current generator, power-on reset circuitry, a two-wire interface and control logic block, a bias current generator and automatic power control loop, and an analog reference block.



B0072-02

Figure 1. Simplified Block Diagram of the ONET1191V

## EQUALIZER

The data signal can be applied to an input equalizer by means of the input signal pins DIN+/DIN–, which provide on-chip differential 100-Ω line termination. The equalizer is enabled by setting EQENB = 0 (bit 1 of register 0). Equalization of up to 300 mm (12 inches) of microstrip or stripline transmission line on FR4 printed circuit boards can be achieved. The amount of equalization is digitally controlled by the two-wire interface and control logic block and depends on the register settings EQADJ[0..7] (register 3). The equalizer can also be turned off and bypassed by setting EQENB = 1. For details about the equalizer settings, see [Table 6](#).

## HIGH-SPEED CURRENT MODULATOR

The output of the equalizer is applied to the high-speed current modulator. The limiting gain stage ensures sufficient drive amplitude and edge speed for driving the current modulator differential pair.

The modulation current is sunk from the common-emitter node of the named differential pair by means of a modulation current generator, which is digitally controlled by the two-wire interface and control logic block.

The collector nodes of the differential pair are connected to the output pins MOD+/MOD–, which include on-chip  $2 \times 55\text{-}\Omega$  back-termination to VCC. The 55-Ω back-termination helps to suppress signal distortion caused by double reflections for VCSEL diodes with impedances from 50 Ω through 75 Ω.

## MODULATION CURRENT GENERATOR

The modulation current generator provides the current for the current modulator described previously. The circuit is digitally controlled by the two-wire interface and control logic block.

An 8-bit-wide control bus, MODC, is used to set the desired modulation current. Furthermore, two modulation current ranges are selected by means of the MODR signal. The ENA signal enables or disables the modulation current generator.

The modulation current can be disabled by setting the DIS input pin to a high level. The modulation current is also disabled in a fault condition if the fault detection enable register flag FLTEN is set.

For more information about the register functionality, see the register mapping description in [Table 6](#).

## TWO-WIRE INTERFACE AND CONTROL LOGIC

The ONET1191V uses a two-wire serial interface for digital control. A simplified block diagram of this interface is shown in [Figure 2](#). The two circuit inputs, SDA and SCK, are driven, respectively, by the serial data and serial clock from a microcontroller, for example. Both inputs include 100-kΩ pullup resistors to VCC. For driving these inputs, an open-drain output is recommended.

A write cycle consists of a START command, three address bits with MSB first, 8 data bits with MSB first, and a STOP command. In idle mode, both the SDA and SCK lines are at a high level.

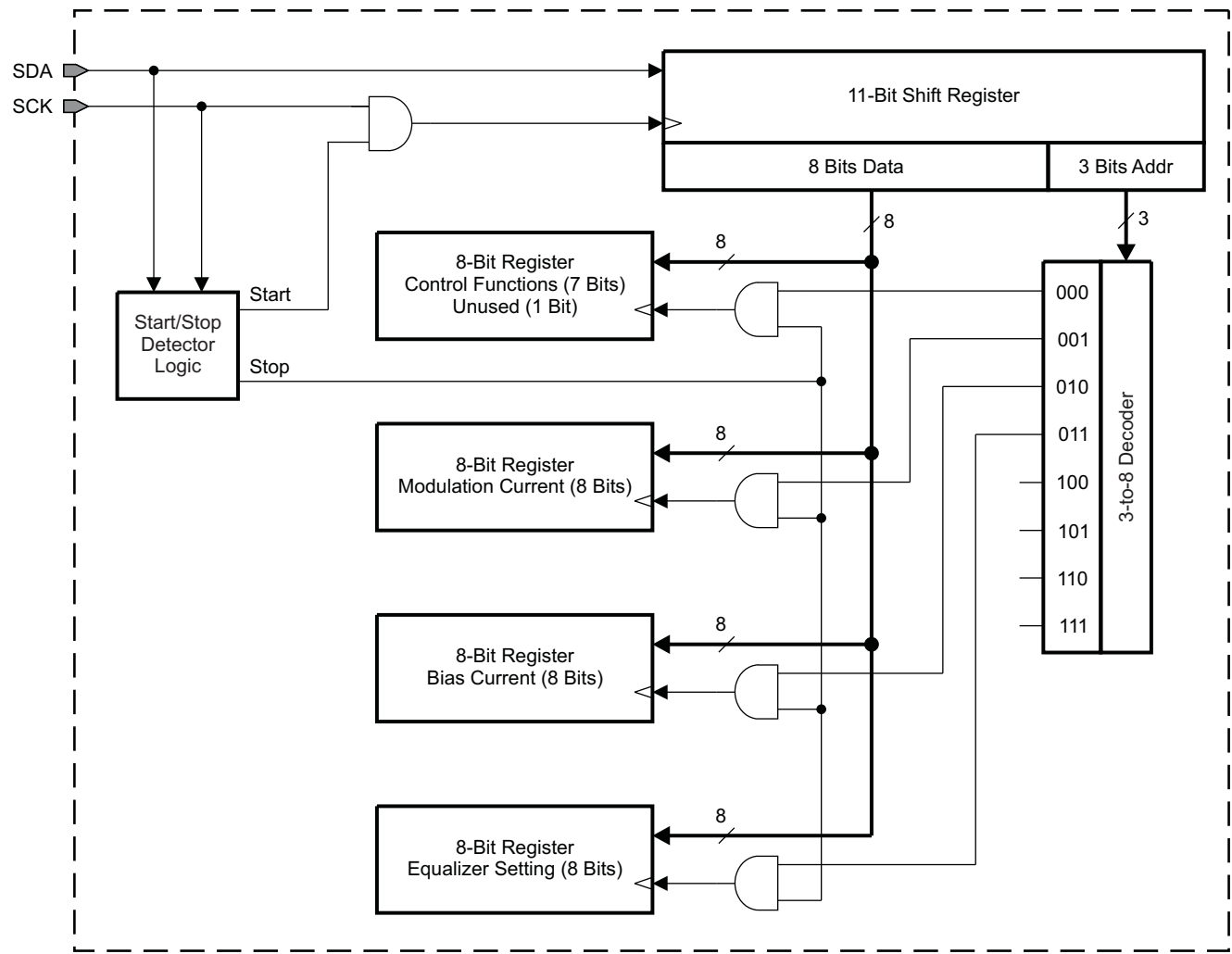
A START command is initiated by the falling edge of SDA with SCK at a high level, transitioning to a low level.

Bits are clocked into an 11-bit-wide shift register during the high level of the serial clock, SCK.

A STOP command is detected on the rising edge of SDA after SCK has changed from a low to a high level.

At the time of detection of a STOP command, the eight data bits from the shift register are copied to a selected 8-bit register. Register selection occurs according to the three address bits in the shift register, which are decoded to eight independent select signals using a 3-to-8 decoder block.

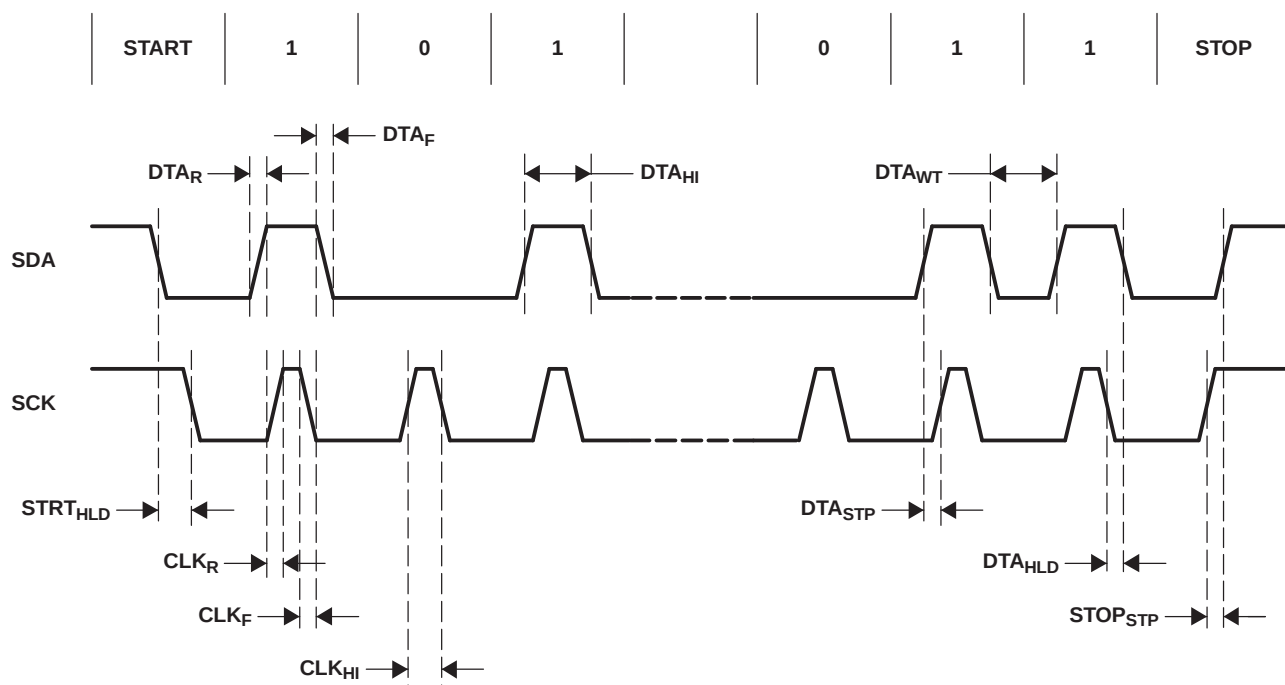
In the ONET1191V, addresses 0 (000b) through 3 (011b) are used.



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**Figure 2. Simplified Two-Wire Interface Block Diagram**

The timing definition for the serial data signal SDA and the serial clock signal SCK is shown in [Figure 3](#). The corresponding timing requirements are listed in [Table 1](#).



T0077-01

Figure 3. Two-Wire Interface Timing Diagram

Table 1. Two-Wire Interface Timing

| PARAMETER                           | DESCRIPTION              | MIN | MAX | UNIT |
|-------------------------------------|--------------------------|-----|-----|------|
| STRT <sub>HLD</sub>                 | START hold time          | 10  |     | ns   |
| CLK <sub>R</sub> , DTA <sub>R</sub> | Clock and data rise time |     | 10  | ns   |
| CLK <sub>F</sub> , DTA <sub>F</sub> | Clock and data fall time |     | 10  | ns   |
| CLK <sub>HI</sub>                   | Clock high time          | 50  |     | ns   |
| DTA <sub>HI</sub>                   | Data high time           | 100 |     | ns   |
| DTA <sub>STP</sub>                  | Data setup time          | 10  |     | ns   |
| DTA <sub>WT</sub>                   | Data wait time           | 50  |     | ns   |
| DTA <sub>HLD</sub>                  | Data hold time           | 10  |     | ns   |
| STOP <sub>STP</sub>                 | STOP setup time          | 10  |     | ns   |

## REGISTER MAPPING

The register mapping for the register addresses 0 (000b) through 3 (011b) are shown in [Table 2](#) through [Table 5](#). [Table 6](#) describes the circuit functionality based on the register settings.

Table 2. Register 0 (000b) Mapping

| address 0 (000b) |       |       |       |       |       |       |       |
|------------------|-------|-------|-------|-------|-------|-------|-------|
| bit 7            | bit 6 | bit 5 | bit 4 | bit 3 | bit 2 | bit 1 | bit 0 |
| ENA              | PDP   | PDR   | OLE   | FLTEN | MODR  | EQENB | —     |

Table 3. Register 1 (001b) Mapping

| address 1 (001b) |       |       |       |       |       |       |       |
|------------------|-------|-------|-------|-------|-------|-------|-------|
| bit 7            | bit 6 | bit 5 | bit 4 | bit 3 | bit 2 | bit 1 | bit 0 |
| MODC7            | MODC6 | MODC5 | MODC4 | MODC3 | MODC2 | MODC1 | MODC0 |

**Table 4. Register 2 (010b) Mapping**

| address 2 (010b) |        |        |        |        |        |        |        |
|------------------|--------|--------|--------|--------|--------|--------|--------|
| bit 7            | bit 6  | bit 5  | bit 4  | bit 3  | bit 2  | bit 1  | bit 0  |
| BIASC7           | BIASC6 | BIASC5 | BIASC4 | BIASC3 | BIASC2 | BIASC1 | BIASC0 |

**Table 5. Register 3 (011b) Mapping**

| address 3 (011b) |        |        |        |        |        |        |        |
|------------------|--------|--------|--------|--------|--------|--------|--------|
| bit 7            | bit 6  | bit 5  | bit 4  | bit 3  | bit 2  | bit 1  | bit 0  |
| EQADJ7           | EQADJ6 | EQADJ5 | EQADJ4 | EQADJ3 | EQADJ2 | EQADJ1 | EQADJ0 |

**Table 6. Register Functionality**

| SYMBOL | REGISTER                         | FUNCTION                                                                                                                                                                                                                                                                                                 |
|--------|----------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| ENA    | Enable                           | Enables chip when set to 1. Can be toggled low to reset a fault condition.                                                                                                                                                                                                                               |
| PDP    | Photodiode polarity              | Photodiode polarity bit:<br>1 = photodiode cathode connected to V <sub>CC</sub><br>0 = photodiode anode connected to GND                                                                                                                                                                                 |
| PDR    | Photodiode current range         | Photodiode current range bit:<br>With coupling ratio CR between VCSEL bias current and photodiode current = 30<br>1 = 12 µA–640 µA with 2.5 µA resolution<br>0 = 2.5 µA–12 8µA with 0.5µA resolution                                                                                                     |
| OLE    | Open loop enable                 | Open-loop enable bit:<br>1 = open-loop bias current control<br>0 = closed-loop bias current control                                                                                                                                                                                                      |
| FLTEN  | Fault detection enable           | Fault detection enable bit:<br>1 = fault detection on<br>0 = fault detection off                                                                                                                                                                                                                         |
| MODR   | Modulation tail current range    | Laser modulation tail current range:<br>1 = 0 mA–40 mA<br>0 = 0 mA–20 mA                                                                                                                                                                                                                                 |
| EQENB  | Equalizer enable                 | Equalizer enable bit<br>1 = equalizer disabled<br>0 = equalizer enabled                                                                                                                                                                                                                                  |
| MODC7  | Modulation current bit 7 (MSB)   | Modulation current setting:<br><br>MODR = 1:<br>Modulation current up to 40 mA in 156-µA steps<br><br>MODR = 0:<br>Modulation current up to 20 mA in 78-µA steps                                                                                                                                         |
| MODC6  | Modulation current bit 6         |                                                                                                                                                                                                                                                                                                          |
| MODC5  | Modulation current bit 5         |                                                                                                                                                                                                                                                                                                          |
| MODC4  | Modulation current bit 4         |                                                                                                                                                                                                                                                                                                          |
| MODC3  | Modulation current bit 3         |                                                                                                                                                                                                                                                                                                          |
| MODC2  | Modulation current bit 2         |                                                                                                                                                                                                                                                                                                          |
| MODC1  | Modulation current bit 1         |                                                                                                                                                                                                                                                                                                          |
| MODC0  | Modulation current bit 0 (LSB)   |                                                                                                                                                                                                                                                                                                          |
| BIASC7 | Bias current bit 7 (MSB)         | <b>Closed loop (APC):</b><br>Coupling ratio $CR = I_{BIAS-VCSEL}/I_{PD}$<br>PDR = 0, BIASC = 0..255, $I_{BIAS-VCSEL} \leq 20$ mA:<br>$I_{BIAS-VCSEL} = 0.5 \mu A \times CR \times BIASC$<br>PDR = 1, BIASC = 0..255, $I_{BIAS-VCSEL} \leq 20$ mA:<br>$I_{BIAS-VCSEL} = 2.5 \mu A \times CR \times BIASC$ |
| BIASC6 | Bias current bit 6               |                                                                                                                                                                                                                                                                                                          |
| BIASC5 | Bias current bit 5               |                                                                                                                                                                                                                                                                                                          |
| BIASC4 | Bias current bit 4               |                                                                                                                                                                                                                                                                                                          |
| BIASC3 | Bias current bit 3               |                                                                                                                                                                                                                                                                                                          |
| BIASC2 | Bias current bit 2               |                                                                                                                                                                                                                                                                                                          |
| BIASC1 | Bias current bit 1               |                                                                                                                                                                                                                                                                                                          |
| BIASC0 | Bias current bit 0 (LSB)         |                                                                                                                                                                                                                                                                                                          |
| EQADJ7 | Equalizer adjustment bit 7 (MSB) | <b>Open loop:</b> $I_{BIAS-VCSEL} = 75 \mu A \times BIASC$<br><br><b>Equalizer adjustment setting</b><br><br>EQENB = 1<br>Equalizer is turned off and bypassed                                                                                                                                           |
| EQADJ6 | Equalizer adjustment bit 6       |                                                                                                                                                                                                                                                                                                          |
| EQADJ5 | Equalizer adjustment bit 5       |                                                                                                                                                                                                                                                                                                          |
| EQADJ4 | Equalizer adjustment bit 4       |                                                                                                                                                                                                                                                                                                          |
| EQADJ3 | Equalizer adjustment bit 3       |                                                                                                                                                                                                                                                                                                          |

**Table 6. Register Functionality (continued)**

| SYMBOL | REGISTER                         | FUNCTION                                                                              |
|--------|----------------------------------|---------------------------------------------------------------------------------------|
| EQADJ2 | Equalizer adjustment bit 2       | EQENB = 0<br>Maximum equalization for 0000 0000<br>Minimum equalization for 1111 1111 |
| EQADJ1 | Equalizer adjustment bit 1       |                                                                                       |
| EQADJ0 | Equalizer adjustment bit 0 (LSB) |                                                                                       |

## BIAS CURRENT GENERATION AND APC LOOP

The bias current generation and APC loop are controlled by means of the two-wire interface. In open-loop operation, selected by setting OLE = 1 (bit 4 of register 0), the bias current is set directly by the 8-bit-wide control word BIASC[0..7] (register 2). In automatic power control mode, selected by setting OLE = 0, the bias current depends on the register settings BIASC[0..7] and the coupling ratio (CR) between the VCSEL bias current and the photodiode current.  $CR = I_{BIAS-VCSEL}/I_{PD}$ .

Two photodiode current ranges can be selected by means of the PDR register (bit 5 of register 0). The photodiode range should be chosen to keep the laser bias control DAC close to the center of its range. This keeps the laser bias current setpoint resolution high and the loop settling time constant within specification.

For details regarding the bias current setting in open- as well as in closed-loop mode, see [Table 6](#).

In closed-loop mode, the photodiode polarity bit, PDP, must be set for common-anode or common-cathode configuration to ensure proper operation. In open-loop mode, if a photodiode is present, the photodiode polarity bit must be set to the opposite setting.

## ANALOG REFERENCE

The ONET1191V VCSEL driver is supplied by a single 3.3-V  $\pm 10\%$  supply voltage connected to the VCC pins. This voltage is referred to ground (GND).

On-chip bandgap voltage circuitry generates a reference voltage, independent of the supply voltage, from which all other internally required voltages and bias currents are derived.

An external zero-temperature-coefficient resistor must be connected from the RZTC pin of the device to ground (GND). This resistor is used to generate a precise, zero-TC current, which is required as a reference current for the on-chip DACs.

In order to minimize the module component count, the ONET1191V provides an on-chip temperature sensor. The output voltage of the temperature sensor is available at the TS pin.

The voltage is  $V_{TS} = (8.2 \text{ mV}/^{\circ}\text{C} \times \text{TEMP}) + 1140 \text{ mV}$ , with TEMP given in  $^{\circ}\text{C}$ .

Note that the voltage at TS is not buffered. As a result, TS can only drive capacitive loads.

## POWER-ON RESET AND REGISTER LOADING SEQUENCE

The ONET1191V has power-on-reset circuitry, which ensures that all registers are reset to zero during startup. After the power-on to initialize time ( $t_{INIT1}$ ), the internal registers are ready to be loaded. It is important that the registers are loaded in the following order:

1. Bias current register (register 2, 010b)
2. Modulation current register (register 1, 001b)
3. Control register (register 0, 000b)
4. Loading of equalizer register (register 3, 011b) is not required.

The part is ready to transmit data after the initialize to transmit time  $t_{INIT2}$ , assuming that the control register enable bit ENA is set to 1 and the disable pin DIS is low.

The ONET1191V can be disabled using either the ENA control register bit or the disable pin DIS. In both cases, the internal registers are not reset. After the disable pin DIS is set low and/or the enable bit ENA is set back to 1, the part returns to its prior output settings.

## LASER SAFETY FEATURES AND FAULT RECOVERY PROCEDURE

The ONET1191V provides built-in laser safety features. The following fault conditions are detected:

- Voltage at MONB exceeds the voltage at RZTC (1.15V).
- Photodiode current exceeds 150% of its set value.
- Bias control DAC drops in value by more than 50% in one step.

If one or more fault conditions occur and the fault enable bit FLTEN is set to 1, the ONET1191V responds by:

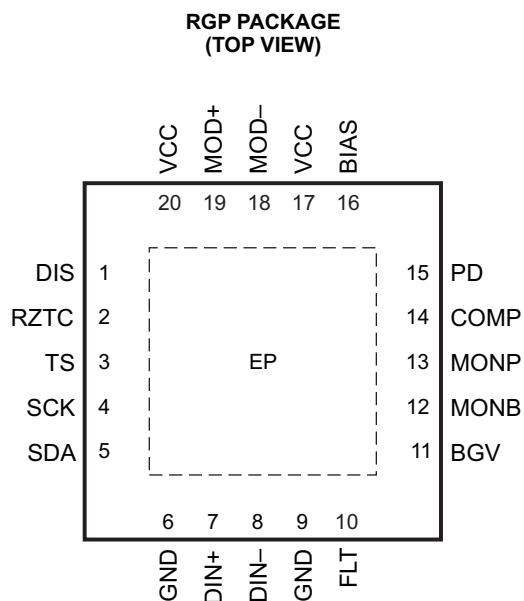
- Setting the VCSEL bias current to zero
- Setting the modulation current to zero
- Asserting and latching the FLT pin

Fault recovery is performed by the following procedure:

1. The disable pin DIS and/or the enable control bit ENA are toggled for at least the fault latch reset time  $t_{\text{RESET}}$ .
2. The FLT pin deasserts while the disable pin DIS is asserted or the enable bit ENA is deasserted.
3. If the fault condition is no longer present, the part returns to normal operation with its prior output settings after the disable negate time  $t_{\text{ON}}$ .
4. If the fault condition is still present, FLT reasserts once DIS is set to a low level, and the part does not return to normal operation.

## PACKAGE

The ONET1191V is packaged in a small-footprint, 4-mm × 4-mm, 20-pin QFN package with a lead pitch of 0,5 mm. The pinout is shown in [Figure 4](#).



P0031-04

**Figure 4. Pinout of ONET1191V in a 4-mm × 4-mm, 20-Pin QFN Package**

## TERMINAL FUNCTIONS

| TERMINAL |          | I/O         | DESCRIPTION                                                                                                                                                                                                                                                                      |
|----------|----------|-------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME     | NO.      |             |                                                                                                                                                                                                                                                                                  |
| BGV      | 11       | Analog-out  | Buffered bandgap voltage with open emitter output. This is a replica of the bandgap voltage at RZTC. For best matching, use the same 28.7-k $\Omega$ resistor to GND as used at RZTC.                                                                                            |
| BIAS     | 16       | Analog      | Sinks average bias current for VCSEL in both APC and open-loop modes. Connect to laser cathode through an inductor. BLM15HG102SN1D recommended.                                                                                                                                  |
| COMP     | 14       | Analog      | Compensation pin used to control the bandwidth of the APC loop. Connect a 0.01- $\mu$ F capacitor to ground.                                                                                                                                                                     |
| DIN+     | 7        | Analog-in   | Noninverted data input. On-chip differentially 100- $\Omega$ terminated to DIN–. Must be ac-coupled.                                                                                                                                                                             |
| DIN–     | 8        | Analog-in   | Inverted data input. On-chip differentially 100- $\Omega$ terminated to DIN+. Must be ac-coupled.                                                                                                                                                                                |
| DIS      | 1        | Digital-in  | Disables both bias and modulation currents when set to high state. Toggle to reset a fault condition.                                                                                                                                                                            |
| FLT      | 10       | Digital-out | Fault detection flag.                                                                                                                                                                                                                                                            |
| GND      | 6, 9, EP | Supply      | Circuit ground. Exposed die pad (EP) must be grounded.                                                                                                                                                                                                                           |
| MOD+     | 19       | CML-out     | Noninverted modulation current output. On-chip, 55- $\Omega$ back-terminated to VCC.                                                                                                                                                                                             |
| MOD–     | 18       | CML-out     | Inverted modulation current output. On-chip, 55- $\Omega$ back-terminated to VCC.                                                                                                                                                                                                |
| MONB     | 12       | Analog-out  | Bias current monitor. Sources a 3.3% replica of the bias current. Connect an external resistor to ground (GND). If the voltage at this pin exceeds 1.15 V, a fault is triggered. Typically, choose a resistor to give MONB voltage of 0.8 V at the maximum desired bias current. |
| MONP     | 13       | Analog-out  | Photodiode current monitor. Sources a 50% replica of the photodiode current when PDR = 1 and a 250% replica when PDR = 0. Connect an external resistor (5 k $\Omega$ typical) to ground (GND).                                                                                   |
| PD       | 15       | Analog      | Photodiode input. Pin can source or sink current dependent on PDP register setting. PDP = 0: source; PDP = 1: sink. Pin supplies >1.5-V reverse bias.                                                                                                                            |
| RZTC     | 2        | Analog      | Connect external zero-TC, 28.7-k $\Omega$ resistor to ground (GND). Used to generate a defined zero-TC reference current for internal DACs.                                                                                                                                      |
| SCK      | 4        | Digital-in  | Two-wire interface serial clock. Includes a 100-k $\Omega$ pullup resistor to VCC.                                                                                                                                                                                               |
| SDA      | 5        | Digital-in  | Two-wire interface serial data input. Includes a 100-k $\Omega$ pullup resistor to VCC.                                                                                                                                                                                          |
| TS       | 3        | Analog-out  | Temperature sensor output. Not buffered, capacitive load only.                                                                                                                                                                                                                   |
| VCC      | 17, 20   | Supply      | 3.3-V $\pm$ 10% supply voltage                                                                                                                                                                                                                                                   |

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                                                                                                                                                                                                                                                                                                                      |                                                                                                                 | VALUE     | UNIT     |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------|-----------|----------|
| V <sub>CC</sub>                                                                                                                                                                                                                                                                                                      | Supply voltage <sup>(2)</sup>                                                                                   | –0.3 to 4 | V        |
| V <sub>DIS</sub> , V <sub>RZTC</sub> , V <sub>TS</sub> , V <sub>SCK</sub> , V <sub>SDA</sub> , V <sub>DIN+</sub> , V <sub>DIN–</sub> , V <sub>FLT</sub> , V <sub>BGV</sub> , V <sub>MONB</sub> , V <sub>MONP</sub> , V <sub>CAPC</sub> , V <sub>PD</sub> , V <sub>BIAS</sub> , V <sub>MOD+</sub> , V <sub>MOD–</sub> | Voltage at DIS, RZTC, TS, SCK, SDA, DIN+, DIN–, FLT, BGV, MONB, MONP, CAPC, PD, BIAS, MOD+, MOD– <sup>(2)</sup> | –0.3 to 4 | V        |
| ESD                                                                                                                                                                                                                                                                                                                  | ESD rating at all pins                                                                                          | 2         | kV (HBM) |
| T <sub>J,max</sub>                                                                                                                                                                                                                                                                                                   | Maximum junction temperature                                                                                    | 125       | °C       |
| T <sub>stg</sub>                                                                                                                                                                                                                                                                                                     | Storage temperature range                                                                                       | –65 to 85 | °C       |
| T <sub>A</sub>                                                                                                                                                                                                                                                                                                       | Characterized free-air operating temperature range                                                              | –40 to 85 | °C       |
| T <sub>LEAD</sub>                                                                                                                                                                                                                                                                                                    | Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds                                                    | 260       | °C       |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

**RECOMMENDED OPERATING CONDITIONS**

|                   |                                       |                                              | MIN  | NOM  | MAX  | UNIT       |
|-------------------|---------------------------------------|----------------------------------------------|------|------|------|------------|
| V <sub>CC</sub>   | Supply voltage                        |                                              | 2.9  | 3.3  | 3.6  | V          |
| V <sub>IH</sub>   | Digital input high voltage            | DIS, SCK, SDA                                | 2    |      |      | V          |
| V <sub>IL</sub>   | Digital input low voltage             | DIS, SCK, SDA                                |      |      | 0.8  | V          |
|                   | Bias output headroom voltage          | V <sub>BIAS</sub> – GND                      | 300  |      |      | mV         |
|                   | Photodiode current range              | Control bit PDR = 1, step size = 2.5 $\mu$ A | 12   |      | 640  | $\mu$ A    |
|                   |                                       | Control bit PDR = 0 step size = 0.5 $\mu$ A  | 2.5  |      | 128  |            |
| R <sub>RZTC</sub> | Zero-TC resistor value <sup>(1)</sup> | 1.15-V bandgap bias across resistor          | 28.4 | 28.7 | 29   | k $\Omega$ |
| V <sub>IN</sub>   | Differential input voltage swing      | Control bit EQENA = 1                        | 200  |      | 1200 | mVp-p      |
|                   |                                       | Control bit EQENA = 0                        | 500  |      | 1200 |            |
| t <sub>R-IN</sub> | Input rise time                       | 20%–80%                                      |      | 30   | 55   | ps         |
| t <sub>F-IN</sub> | Input fall time                       | 20%–80%                                      |      | 30   | 55   | ps         |
| T <sub>A</sub>    | Operating free-air temperature        |                                              | –40  |      | 85   | ° C        |

(1) Changing the value alters the DAC ranges.

## DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions; all values are for open-loop operation,  $I_{MODC} = 12\text{ mA}$ ,  $I_{BIASC} = 6\text{ mA}$ , and  $R_{RZTC} = 28.7\text{ k}\Omega$  (unless otherwise noted)

|                        | PARAMETER                                                                        | TEST CONDITIONS                                                                                                     | MIN  | TYP                | MAX  | UNIT |
|------------------------|----------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------|------|--------------------|------|------|
| V <sub>CC</sub>        | Supply voltage                                                                   |                                                                                                                     | 2.9  | 3.3                | 3.6  | V    |
| I <sub>VCC</sub>       | Supply current                                                                   | I <sub>MODC</sub> = 24mA, I <sub>BIASC</sub> = 6 mA, including I <sub>MODC</sub> and I <sub>BIASC</sub> , EQENB = 1 |      | 62                 | 71   | mA   |
|                        |                                                                                  | I <sub>MODC</sub> = 24mA, I <sub>BIASC</sub> = 6mA, including I <sub>MODC</sub> and I <sub>BIASC</sub> , EQENB = 0  |      | 70                 |      |      |
|                        |                                                                                  | Disabled, DIS = high and/or control bit ENA = low, EQENB = 1                                                        |      | 35                 | 42   |      |
| R <sub>IN</sub>        | Data input resistance                                                            | Differential between DIN+/DIN–                                                                                      | 85   | 100                | 125  | Ω    |
| R <sub>OUT</sub>       | Data output resistance                                                           | Single-ended to V <sub>CC</sub>                                                                                     | 45   | 55                 | 65   | Ω    |
|                        | Digital input current                                                            | SCK, SDA, 100-kΩ pullup to V <sub>CC</sub> <sup>(1)</sup>                                                           | –50  |                    | 10   | μA   |
|                        |                                                                                  | DIS <sup>(1)</sup>                                                                                                  | –10  |                    | 10   | μA   |
| V <sub>OH</sub>        | Digital output high voltage                                                      | FLT, I <sub>SOURCE</sub> = 500 μA                                                                                   | 2.4  |                    |      | V    |
| V <sub>OL</sub>        | Digital output low voltage                                                       | FLT, I <sub>SINK</sub> = 500 μA                                                                                     |      |                    | 0.4  | V    |
| I <sub>BIAS-DIS</sub>  | Bias current during disable                                                      |                                                                                                                     |      |                    | 100  | μA   |
| I <sub>BIAS-MIN</sub>  | Minimum bias current                                                             | See <sup>(2)</sup>                                                                                                  |      |                    | 0.2  | mA   |
| I <sub>BIAS-MAX</sub>  | Maximum bias current                                                             | DAC set to maximum, open- and closed-loop                                                                           | 14   | 20                 |      | mA   |
| V <sub>PD</sub>        | Photodiode reverse bias voltage                                                  | APC active, I <sub>PD</sub> = max                                                                                   | 1.5  | 2.3                |      | V    |
|                        | Photodiode fault current level, percent of target I <sub>PD</sub> <sup>(1)</sup> |                                                                                                                     |      | 150%               |      |      |
| V <sub>TS</sub>        | Temperature sensor voltage range                                                 | –40°C to 120°C junction temperature, capacitive load only, with midscale calibration. <sup>(1)</sup>                | 0.5  |                    | 2.5  | V    |
|                        | Temperature sensor accuracy                                                      | With midscale calibration <sup>(1)</sup>                                                                            |      | ±3                 |      | °C   |
| I <sub>TS</sub>        | Temperature sensor drive current                                                 | Source or sink <sup>(1)</sup>                                                                                       | –1   |                    | 1    | μA   |
|                        | Photodiode current monitor ratio                                                 | I <sub>MONP</sub> /I <sub>PD</sub> with control bit PDR = 1                                                         | 40%  | 50%                | 60%  |      |
|                        |                                                                                  | I <sub>MONP</sub> /I <sub>PD</sub> with control bit PDR = 0                                                         | 200% | 265%               | 300% |      |
|                        | Bias current monitor ratio                                                       | I <sub>MONB</sub> /I <sub>BIAS</sub> (nominal 1/30 = 3.3%). 1.2-kΩ sense resistor                                   | 2.7% | 3.3%               | 4%   |      |
| V <sub>CC-RST</sub>    | V <sub>CC</sub> reset threshold voltage                                          | V <sub>CC</sub> voltage level which triggers power-on reset <sup>(1)</sup>                                          | 2.4  | 2.5                | 2.8  | V    |
| V <sub>CC-RSTHYS</sub> | V <sub>CC</sub> reset threshold voltage hysteresis                               |                                                                                                                     |      | 100 <sup>(1)</sup> |      | mV   |
| V <sub>MONB-FLT</sub>  | Fault voltage at MONB                                                            | Fault occurs if voltage at MONB exceeds value                                                                       | 1.05 | 1.15               | 1.25 | V    |

(1) Assured by simulation over process, supply, and temperature variation

(2) The bias current can be set below the specified minimum according to the corresponding register setting described in the register mapping section. However, in closed-loop operation, settings below the specified value may trigger a fault.

## AC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions with 50-Ω output load, open-loop operation,  $I_{\text{MODC}} = 12 \text{ mA}$ ,  $I_{\text{BIASC}} = 6 \text{ mA}$ , and  $R_{\text{RZTC}} = 28.7 \text{ k}\Omega$ , unless otherwise noted. Typical operating condition is at  $V_{\text{CC}} = 3.3 \text{ V}$  and  $T_A = 25^\circ\text{C}$ .

| PARAMETER             | TEST CONDITIONS              | MIN                                                                                                                | TYP | MAX | UNIT                     |
|-----------------------|------------------------------|--------------------------------------------------------------------------------------------------------------------|-----|-----|--------------------------|
| $t_{\text{r-OUT}}$    | Output rise time             |                                                                                                                    | 20  | 30  | ps                       |
| $t_{\text{f-OUT}}$    | Output fall time             |                                                                                                                    | 25  | 30  | ps                       |
| $I_{\text{MOD-MAX}}$  | Maximum modulation current   | Control bit MODR = 1, 50-Ω load                                                                                    | 36  | 45  | mA                       |
|                       |                              | Control bit MODR = 0, 50-Ω load                                                                                    | 18  | 27  |                          |
| $I_{\text{MOD-STEP}}$ | Modulation current step size | Control bit MODR = 1, 50-Ω load                                                                                    | 175 |     | $\mu\text{A}$            |
|                       |                              | Control bit MODR = 0, 50-Ω load                                                                                    | 100 |     |                          |
| DJ                    | Deterministic output jitter  | Control bit EQENB = 1, K28.5 pattern at 11.3 Gbps                                                                  | 4   | 12  | $\text{ps}_{\text{p-p}}$ |
|                       |                              | Control bit EQENB = 0, K28.5 pattern at 11.3 Gbps, maximum equalization with 300-mm FR4 trace                      | 10  | 20  |                          |
| RJ                    | Random output jitter         | 50-Ω load                                                                                                          | 0.5 | 0.8 | $\text{ps}_{\text{RMS}}$ |
| $\tau_{\text{APC}}$   | APC time constant            | $C_{\text{APC}} = 0.01 \mu\text{F}$ , $I_{\text{PD}} = 100 \mu\text{A}$ , PD coupling ratio CR = 40 <sup>(1)</sup> | 200 |     | $\mu\text{s}$            |
| $t_{\text{OFF}}$      | Transmitter disable time     | Rising edge of DIS to $I_{\text{BIAS}} \leq 0.1 \times I_{\text{BIAS-NOMINAL}}$ <sup>(1)</sup>                     | 1   | 5   | $\mu\text{s}$            |
| $t_{\text{ON}}$       | Disable negate time          | Falling edge of DIS to $I_{\text{BIAS}} \geq 0.9 \times I_{\text{BIAS-NOMINAL}}$ <sup>(1)</sup>                    |     | 1   | ms                       |
| $t_{\text{INIT1}}$    | Power-on to initialize       | Power-on to registers ready to be loaded                                                                           | 1   | 10  | ms                       |
| $t_{\text{INIT2}}$    | Initialize to transmit       | Register load STOP command to part ready to transmit valid data <sup>(1)</sup>                                     |     | 2   | ms                       |
| $t_{\text{RESET}}$    | DIS pulse duration           | Time DIS must held high to reset part <sup>(1)</sup>                                                               | 100 |     | ns                       |
| $t_{\text{FAULT}}$    | Fault assert time            | Time from fault condition to FLT high <sup>(1)</sup>                                                               |     | 50  | $\mu\text{s}$            |

(1) Assured by simulation over process, supply, and temperature variation

## TYPICAL CHARACTERISTICS

Typical operating condition is at  $V_{\text{CC}} = 3.3 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $I_{\text{BIASC}} = 6 \text{ mA}$ ,  $I_{\text{MODC}} = 12 \text{ mA}$ , MODR = 0 (unless otherwise noted).

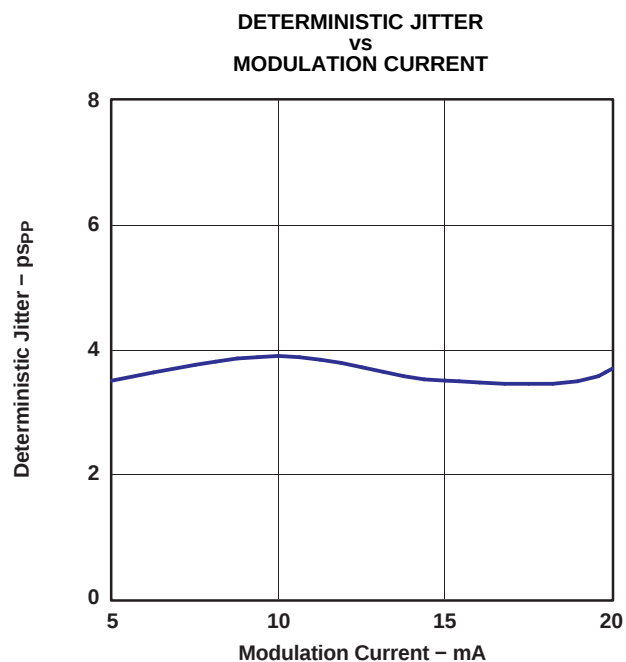


Figure 5.

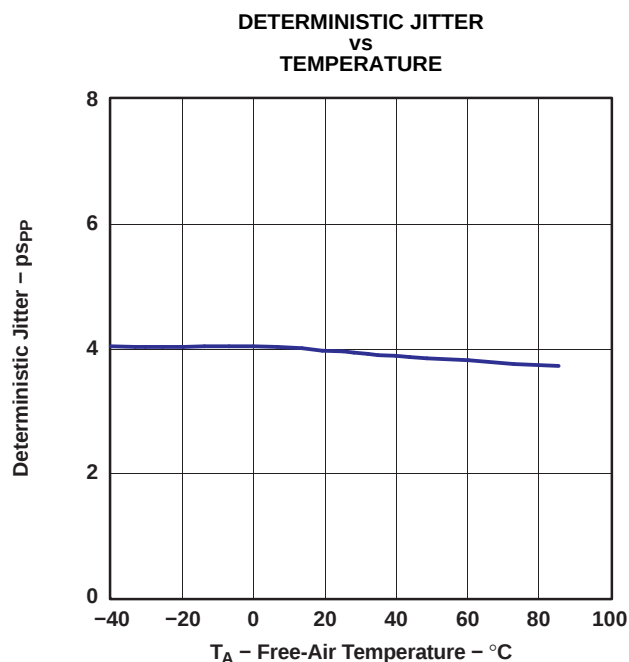


Figure 6.

**TYPICAL CHARACTERISTICS (continued)**

Typical operating condition is at  $V_{CC} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $I_{BIASC} = 6\text{ mA}$ ,  $I_{MODC} = 12\text{ mA}$ ,  $MODR = 0$  (unless otherwise noted).

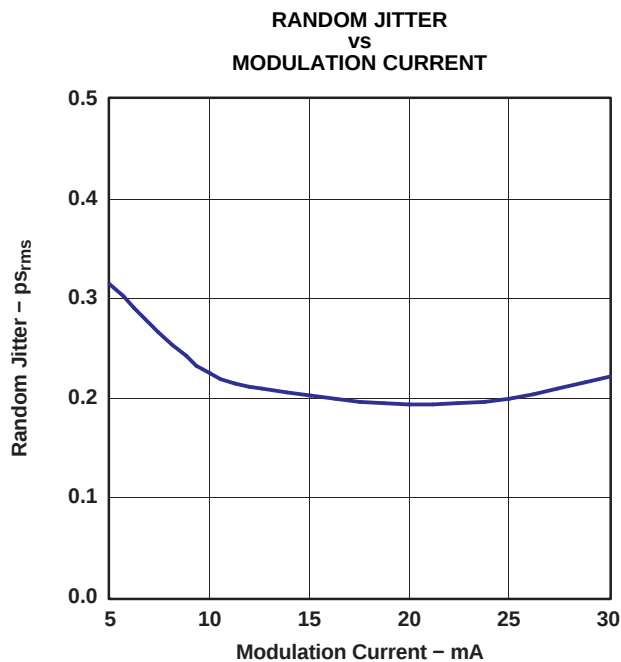


Figure 7.

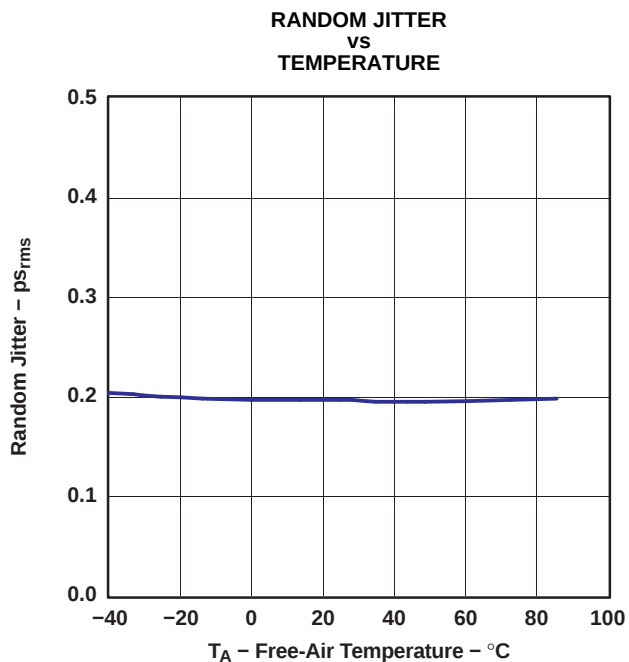


Figure 8.

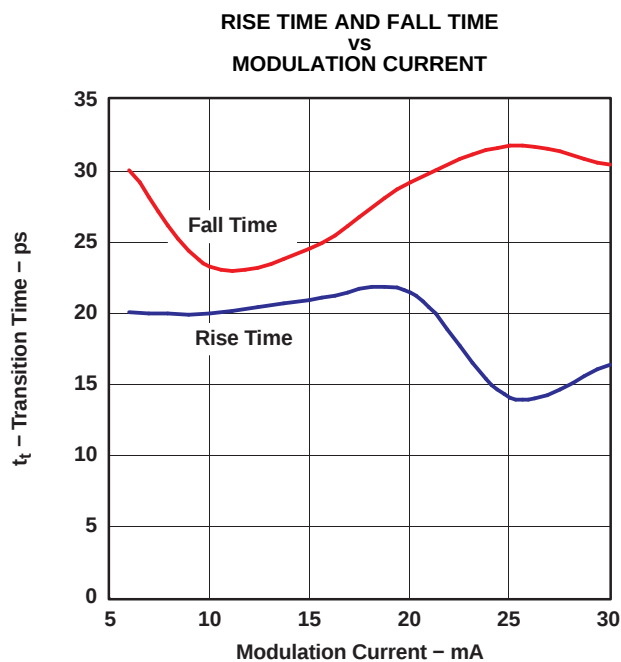


Figure 9.

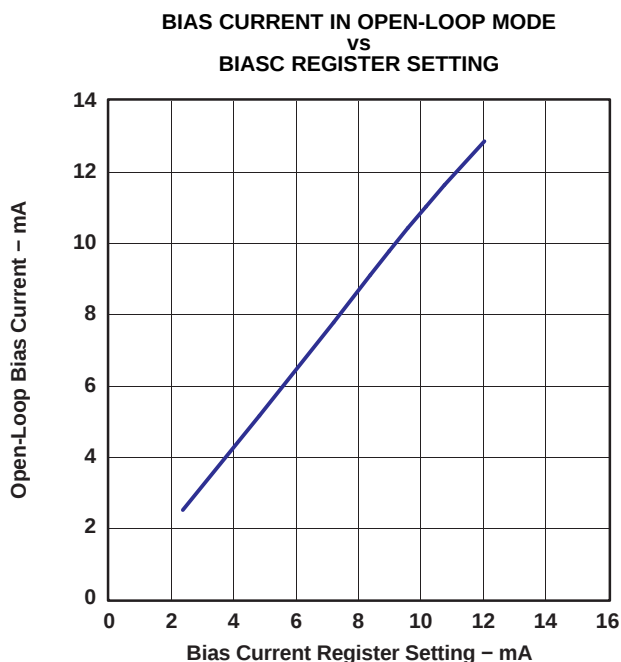


Figure 10.

**TYPICAL CHARACTERISTICS (continued)**

Typical operating condition is at  $V_{CC} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $I_{BIAS} = 6\text{ mA}$ ,  $I_{MODC} = 12\text{ mA}$ ,  $MODR = 0$  (unless otherwise noted).

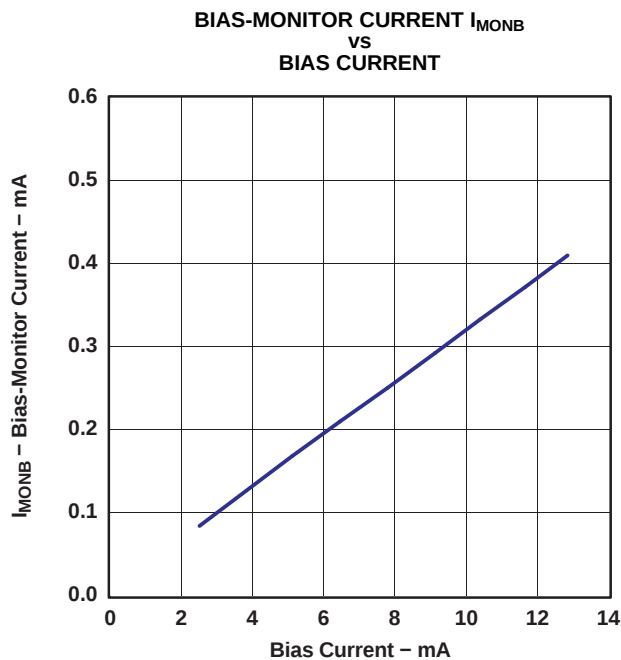


Figure 11.

G016

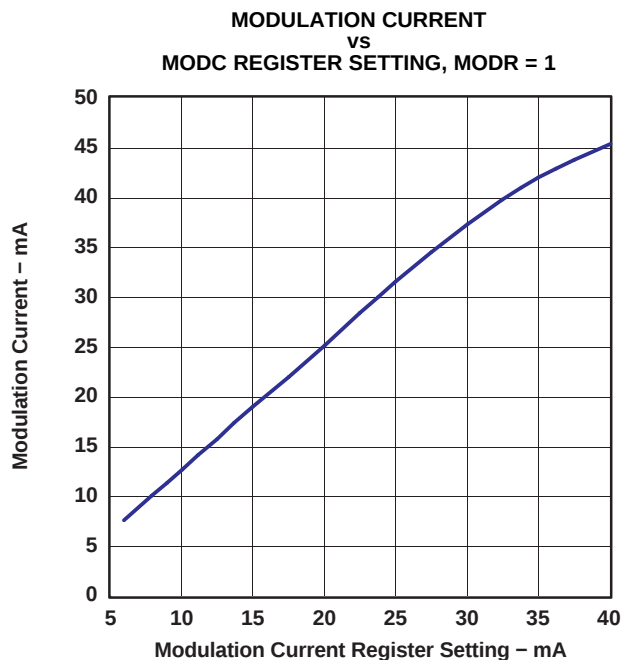


Figure 12.

G007

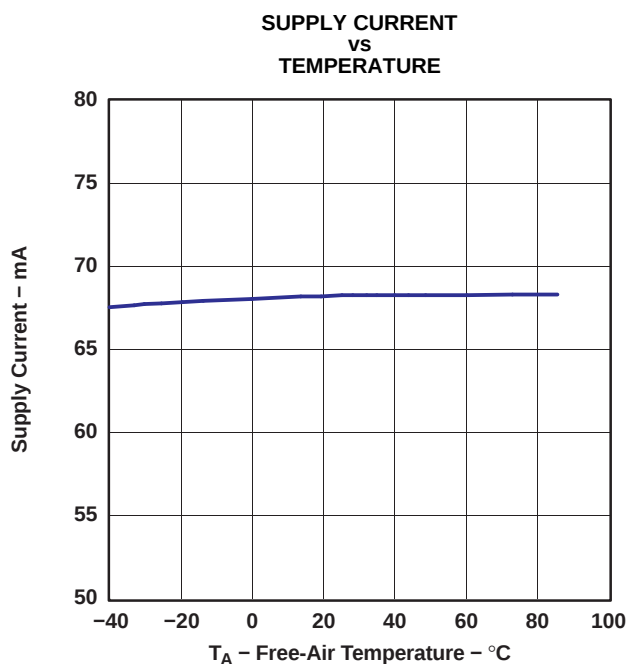


Figure 13.

G008

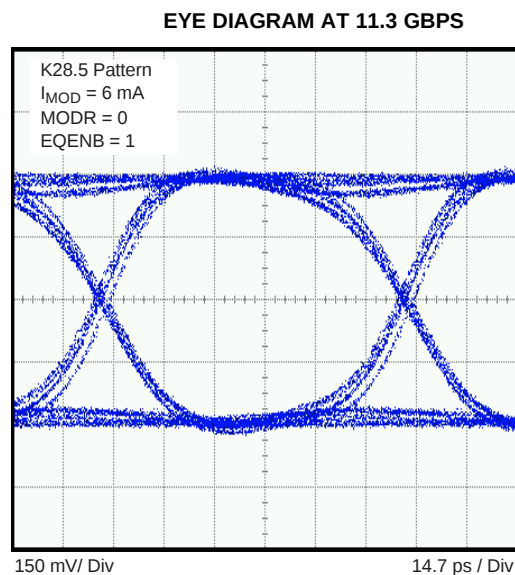
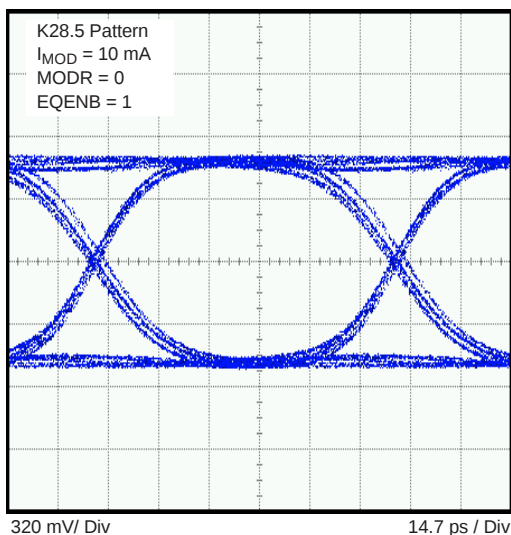


Figure 14.

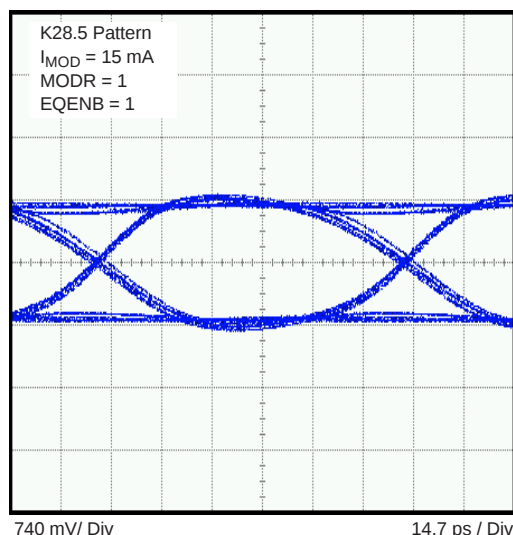
G009

**TYPICAL CHARACTERISTICS (continued)**

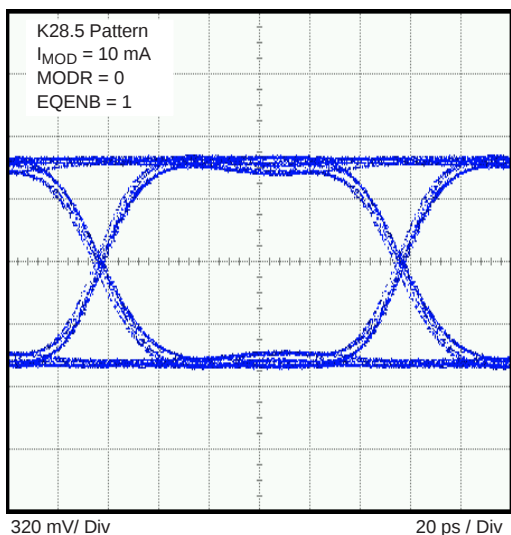
Typical operating condition is at  $V_{CC} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $I_{BIAS} = 6\text{ mA}$ ,  $I_{MODC} = 12\text{ mA}$ ,  $MODR = 0$  (unless otherwise noted).

**EYE DIAGRAM AT 11.3 GBPS**

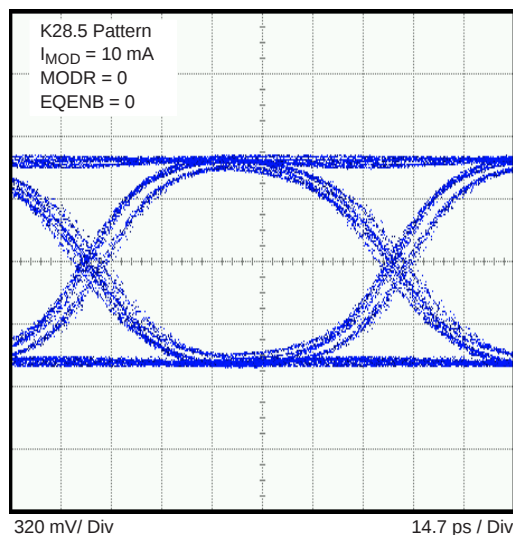
G010

**Figure 15.****EYE DIAGRAM AT 11.3 GBPS**

G011

**Figure 16.****EYE DIAGRAM AT 8.5 GBPS**

G012

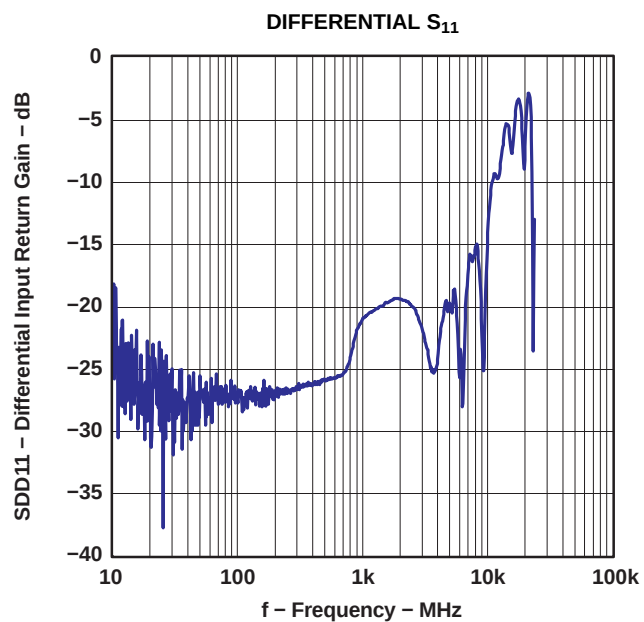
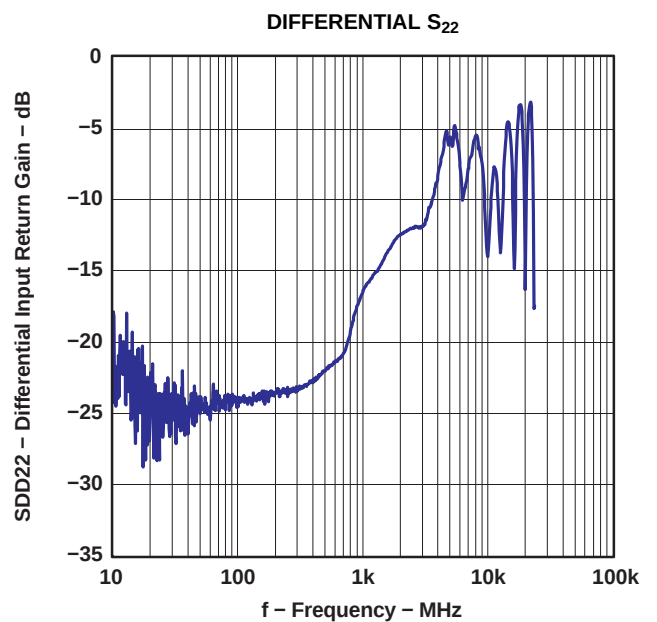
**Figure 17.****EYE DIAGRAM AT 11.3 GBPS  
12" OF FR4 AT INPUTS**

G013

**Figure 18.**

**TYPICAL CHARACTERISTICS (continued)**

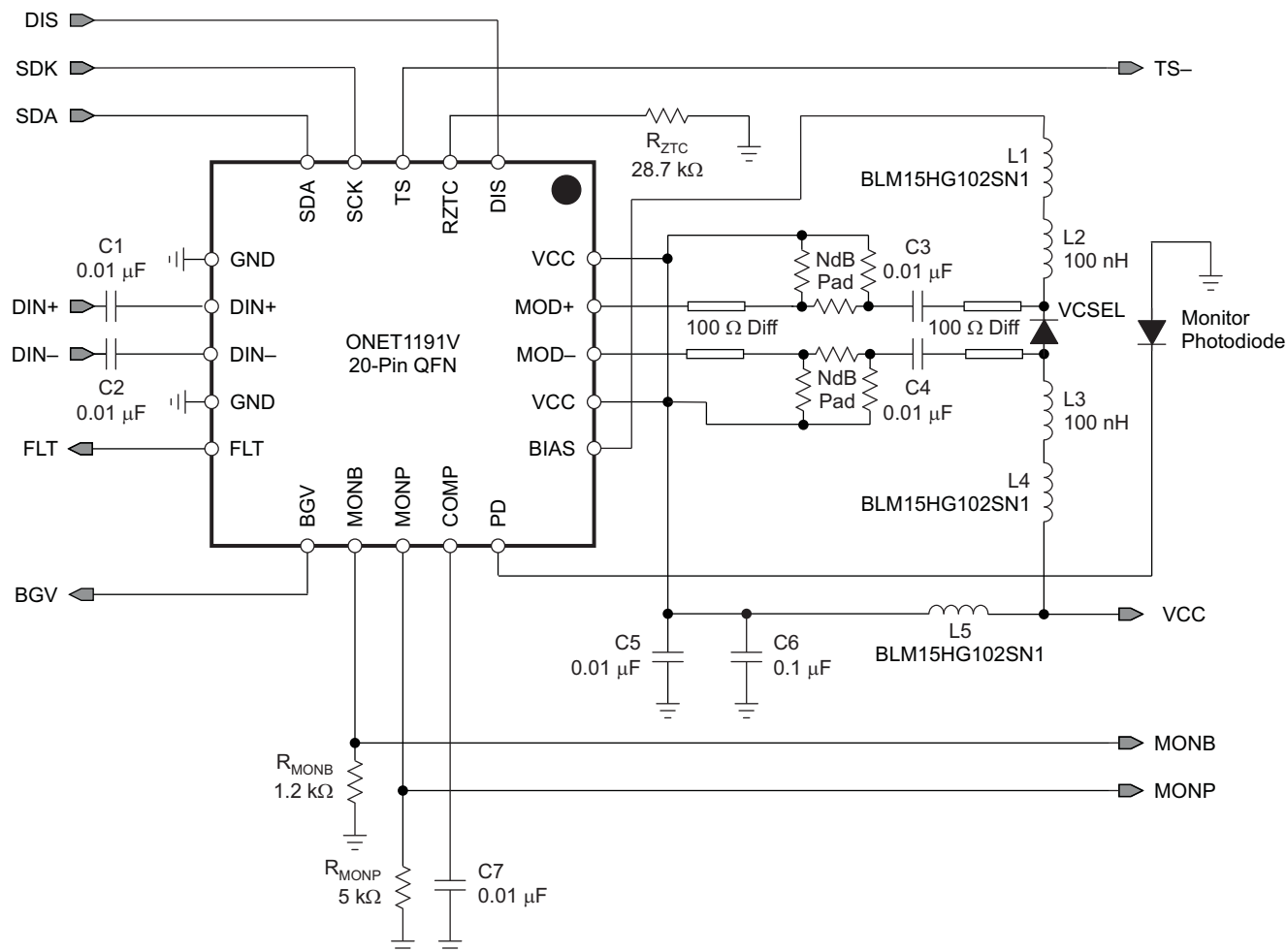
Typical operating condition is at  $V_{CC} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $I_{BIASC} = 6\text{ mA}$ ,  $I_{MODC} = 12\text{ mA}$ ,  $MODR = 0$  (unless otherwise noted).

**Figure 19.****Figure 20.**

## APPLICATION INFORMATION

**Figure 21** shows a typical application circuit using the ONET1191V with a common-cathode VCSEL, biased to  $V_{CC}$ , and driven differentially. The VCSEL driver is controlled via the two-wire interface SDA/SCK by a microprocessor. In a typical application, the FLT, MONP, MONB, and TS outputs are also connected to the microcontroller for transceiver management purposes. The monitor photodiode anode is grounded and the photodiode polarity bit, PDP, must be set to 0.

The component values in [Figure 21](#) are typical examples and may be varied according to the intended application. For best performance, it is recommended to use differential drive. Single-ended VCSEL drive can be implemented by terminating the unused driver output in a resistance that matches the VCSEL series resistance; however, the available VCSEL modulation current is halved.



### Figure 21. Typical Application Circuit With a Common Cathode VCSEL

S0212-01

In the recommended application circuit, the purpose of the attenuator pads is to improve the signal integrity between the VCSEL driver and the VCSEL. Because the VCSEL impedance is reactive, the pads attenuate reflections and provide a better matching impedance for the modulation current outputs. The disadvantage of using the attenuator pads is that the efficiency is reduced. That is, not all of the modulation current at the outputs of the VCSEL driver is available to drive the VCSEL. [Table 7](#) lists the available modulation current at the VCSEL,  $I_{MOD}$ , depending on the modulation tail current register setting,  $I_{MODC}$ , the attenuator value, and the VCSEL series resistance. If care is taken in matching the output impedance of the ONET1191V to the impedance of the VCSEL, and if controlled-impedance transmission lines are used, attenuator pads may not be necessary.

**Table 7.  $I_{MOD}$  vs  $I_{MODC}$  for a Given Attenuator Pad and VCSEL**

| $I_{MODC}$ (mA):<br>REGISTER SETTING | 50- $\Omega$ PAD<br>ATTENUATION (dB) | VCSEL SERIES<br>RESISTANCE ( $\Omega$ ) | $I_{MOD}$ (mA): MODULATION<br>CURRENT AT THE VCSEL |
|--------------------------------------|--------------------------------------|-----------------------------------------|----------------------------------------------------|
| 40                                   | 3                                    | 100                                     | 14.76                                              |
| 40                                   | 6                                    | 100                                     | 10.52                                              |
| 30                                   | 3                                    | 100                                     | 11.07                                              |
| 30                                   | 6                                    | 100                                     | 7.89                                               |
| 20                                   | 3                                    | 100                                     | 7.38                                               |
| 20                                   | 6                                    | 100                                     | 5.26                                               |
| 40                                   | 3                                    | 60                                      | 18.33                                              |
| 40                                   | 6                                    | 60                                      | 13.12                                              |
| 30                                   | 3                                    | 60                                      | 13.75                                              |
| 30                                   | 6                                    | 60                                      | 9.84                                               |
| 20                                   | 3                                    | 60                                      | 9.17                                               |
| 20                                   | 6                                    | 60                                      | 6.56                                               |

## LAYOUT GUIDELINES

For optimum performance, use 50- $\Omega$  transmission lines (100- $\Omega$  differential) for connecting the signal source to the DIN+ and DIN– pins and for connecting the modulation current outputs, MOD+ and MOD–, to the VCSEL. The length of the transmission lines should be kept as short as possible to reduce loss and pattern-dependent jitter.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| ONET1191VRGPT    | ACTIVE        | QFN          | RGP                | 20   | 250            | Green (RoHS<br>& no Sb/Br) | NIPDAU                  | Level-2-260C-1 YEAR  | -40 to 85    | ONET<br>1191V           | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

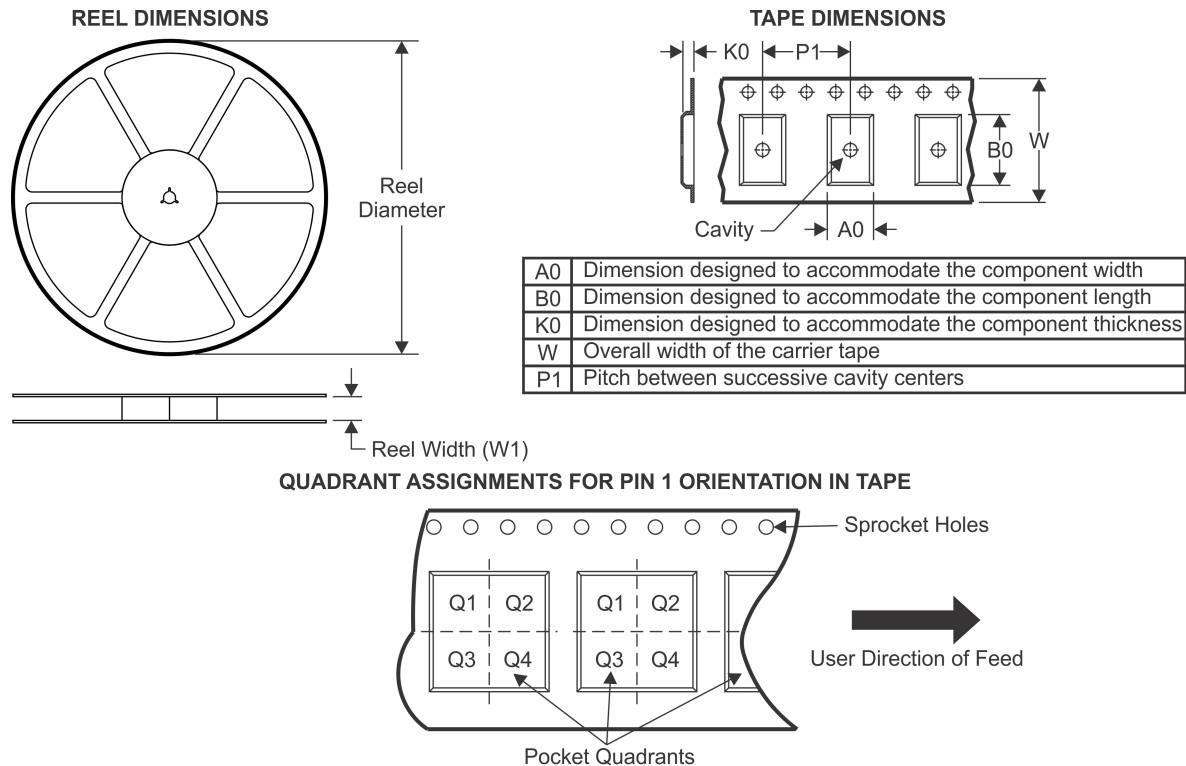
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|-----|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ONET1191VRGPT | QFN          | RGP             | 20   | 250 | 330.0              | 12.4               | 4.3     | 4.3     | 1.5     | 8.0     | 12.0   | Q2            |

## TAPE AND REEL BOX DIMENSIONS

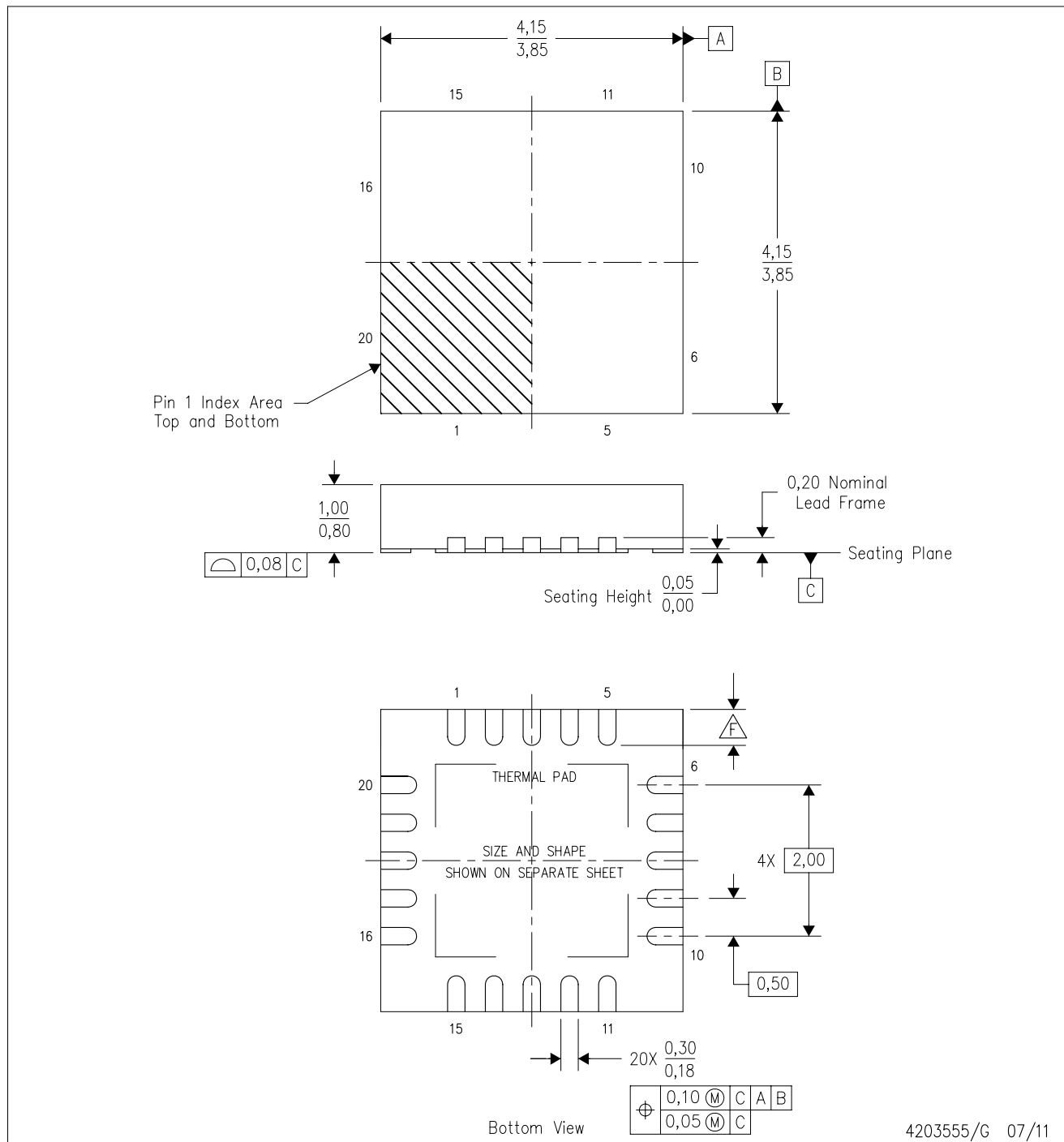


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|-----|-------------|------------|-------------|
| ONET1191VRGPT | QFN          | RGP             | 20   | 250 | 367.0       | 367.0      | 38.0        |

RGP (S-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



4203555/G 07/11

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - QFN (Quad Flatpack No-Lead) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Check thermal pad mechanical drawing in the product datasheet for nominal lead length dimensions.

RGP (S-PVQFN-N20)

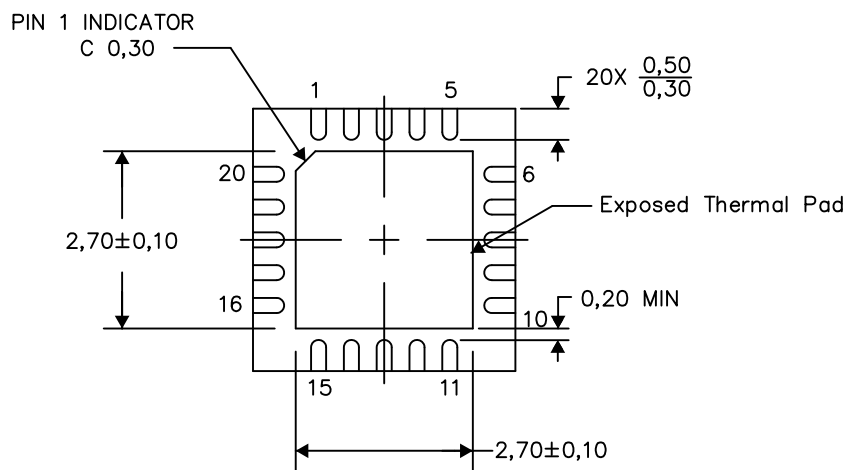
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

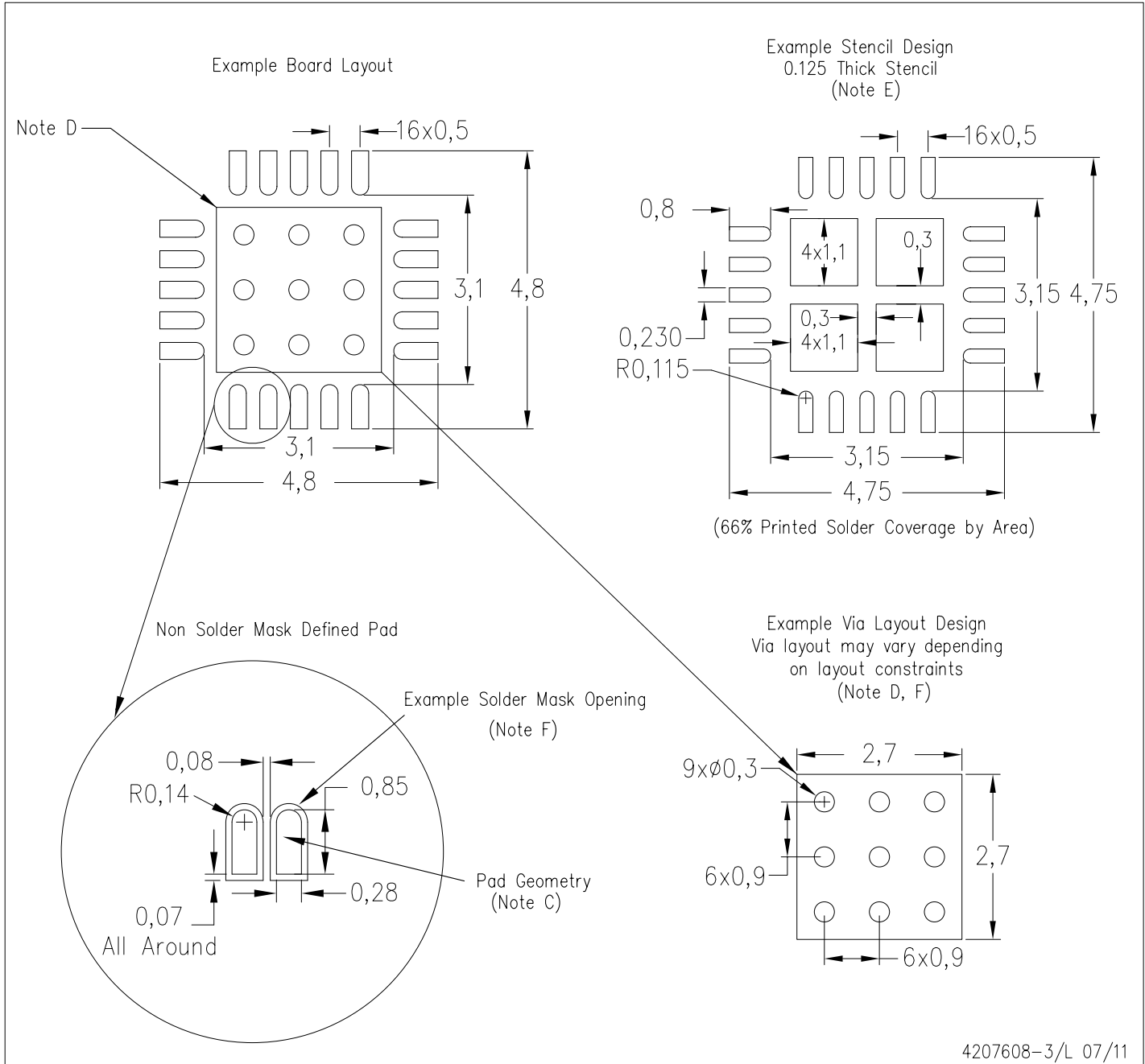
Exposed Thermal Pad Dimensions

4206346-3/AA 11/13

NOTES: A. All linear dimensions are in millimeters

RGP (S-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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